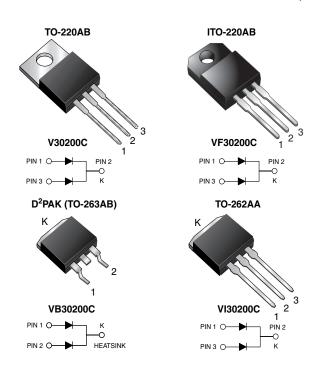


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Vishay General Semiconductor

Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.526 \text{ V}$ at $I_F = 5\text{A}$



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V_{RRM}	200 V					
I _{FSM}	250 A					
V_F at $I_F = 15 A$	0.648 V					
T_J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configurations	Common cathode					

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- · Low thermal resistance



- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

 $\textbf{Case:}\ \ \text{TO-220AB},\ \ \text{ITO-220AB},\ \ D^2\text{PAK}\ \ \ \ \ \ \text{(TO-263AB)},\ \ \text{and}\ \ \ \ \ \ \text{TO-262AA}$

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER			V30200C	VF30200C	VB30200C	VI30200C	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	200				V		
Maximum average forward rectified current per device			30			^			
(fig. 1)	per diode	I _{F(AV)}	15				A		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	250			Α			
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode		E _{AS}	200			mJ			
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		I _{RRM}	0.5			Α			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			1500			V			
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150			°C			

V30200C, VF30200C, VB30200C, VI30200C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	I _R = 10 mA	T _A = 25 °C	V_{BR}	205 min.	-			
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A	T _A = 25 °C	VF	0.691	-			
	I _F = 10 A			0.770	-	T .,		
	I _F = 15 A			0.841	1.10	V		
	I _F = 5 A	T _A = 125 °C		0.526	-			
	I _F = 10 A			0.594	-			
	I _F = 15 A			0.648	0.72			
Reverse current per diode (2)	V _R = 180 V	T _A = 25 °C		2.4	-	μΑ		
		T _A = 125 °C		3.8	-	mA		
	V _R = 200 V	T _A = 25 °C	l _R	5.3	160	μΑ		
		T _A = 125 °C		6.0	12	mA		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30200C	VF30200C	VB30200C	VI30200C	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	5.5	2.0	2.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30200C-E3/4W	2.248	4W	50/tube	Tube			
ITO-220AB	VF30200C-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB30200C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB30200C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI30200C-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

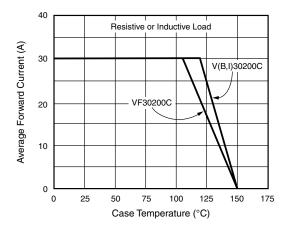


Fig. 1 - Forward Derating Curve

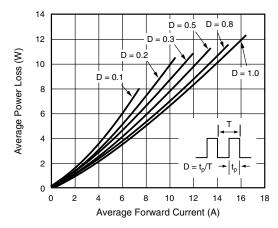


Fig. 2 - Forward Power Loss Characteristics Per Diode

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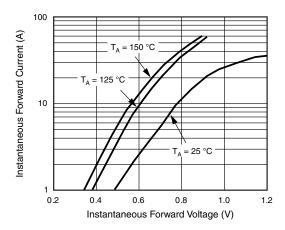


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

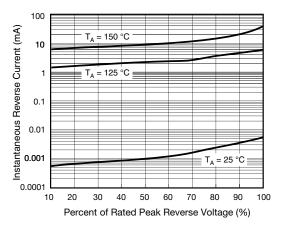


Fig. 4 - Typical Reverse Characteristics Per Diode

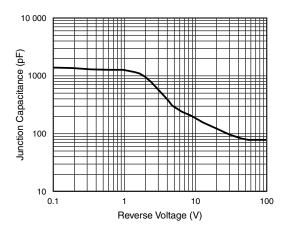


Fig. 5 - Typical Junction Capacitance Per Diode

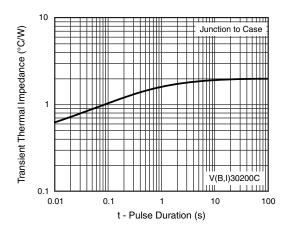


Fig. 6 - Typical Transient Thermal Impedance Per Diode

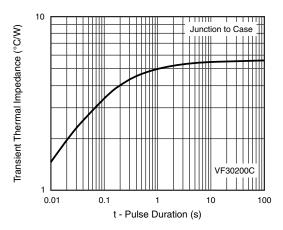


Fig. 7 - Typical Transient Thermal Impedance Per Diode

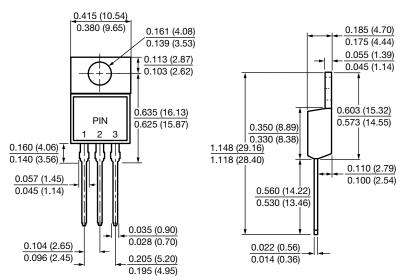


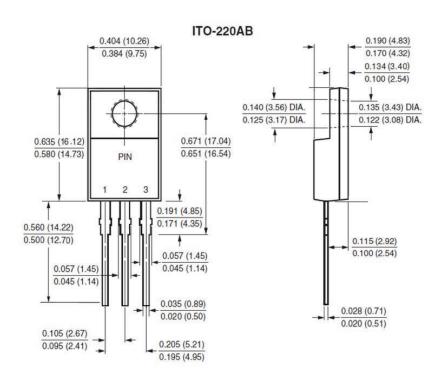
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB

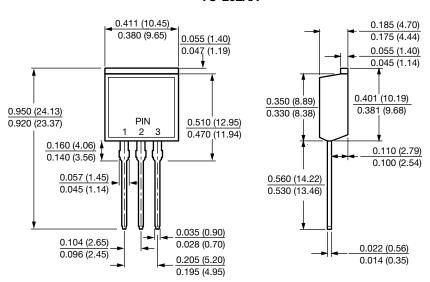




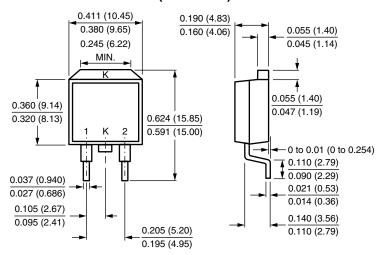


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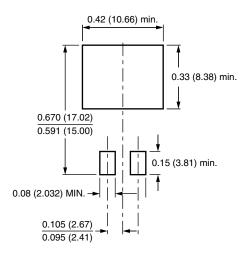
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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